SIEMENS

Dual Operational Amplifier

Features

- Wide common-mode range
- Large supply voltage range
- Wide temperature range (TAA 2762 A)
- High output current
- Large control range
- Internally frequency-compensated
- NPN input with protection diodes
- Open collector output

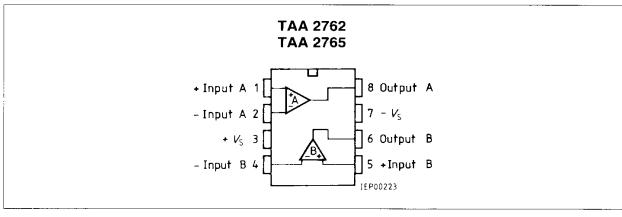
Applications

- Amplifier
- Comparator
- Level converter
- Driver

Туре	Ordering Code	Package
🖸 TAA 2762 A	Q67000-A2499	P-DIP-8
S TAA 2765 A	Q67000-A1031	P-DIP-8

These op amps are particularly economic and versatile. Owing to their excellent performance qualities they are well suited for a wide scope of applications, as in control engineering, automotive electronics, AF circuits, analog computers, etc.

P-DIP-8



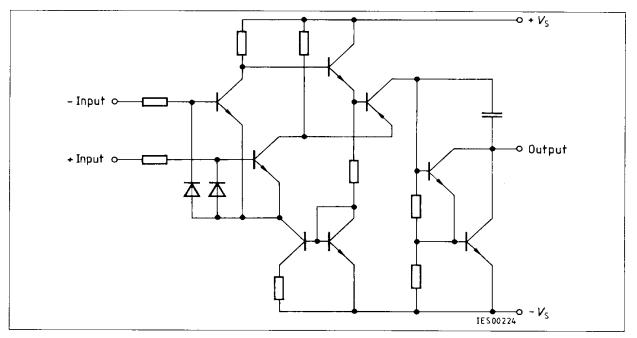
Pin Configuration (top view)

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TAA 2762 TAA 2765



Circuit Diagram of One Op Amp

Absolute Maximum Ratings

Parameter	Symbol	Limit Values	Unit
Supply voltage	Vs	± 18	V
Output current	Ιο	70	mA
Differential input voltage	Vid	± Vs	v
Junction temperature Storage temperature range	Tj Tstg	150 - 55 to 125	C° C
Thermal resistance system - air TAA 2762 A/2765 A	$oldsymbol{R}$ th SA	100	ĸ/w

Operating Range

Supply voltage		Vs	± 2 to ± 15	V
Ambient temperature		TA	- 55 to 125	°C
	TAA 2765 A	T _A	– 25 to 85	C°∣

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Characteristics (TAA 2762)

 $V_{\text{S}} = \pm 5 \text{V}$ to $\pm 15 \text{V}$; $R_{\text{L}} = 2 \text{k}\Omega$, unless otherwise specified

Parameter	Symbol	Limit Values T _A = 25 °C			Limit Values $T_A = -55$ to 125 °C		Unit
		min.	typ.	max.	min.	max.	1
Open-loop supply current consumption, total	Is		0.5	1.5		1.5	mA
Input offset voltage, $R_{\rm G} = 50 \Omega$	Vio	- 4		4	- 6	6	mV
Input offset current Input current	110 11	- 100	± 50 0.3	100 0.7	- 300	300 1.0	nA μA
Control range $V_{s} = \pm 15V$ $R_{L} = 620 \Omega$, $V_{s} = \pm 15V$	V _{Q pp} V _{Q pp}	14.9 14.9		14 12.5	14.8 14.8	- 14 - 12	v v
Input impedance, $f = 1 \text{kHz}$	Z_{1}		200				kΩ
Open-loop voltage gain f = 100 Hz $R \sqcup = 10 \Omega, f = 100 \text{ Hz}$	G vo G vo	85	87 92		80		dB dB
Output reverse current				1		5	μ A
Common-mode input voltage range	Vic	- Vs+2		Vs - 2	- Vs+3	Vs - 3	V
Common-mode rejection	<i>k</i> cmr	80	85			75	dB
Supply voltage rejection, $Gv = 100$	KSVR		25	100		100	μV/V
Temperature coefficient of $V_{\rm IO}$ $R_{\rm G} = 50 \Omega$	α νιο		1	15		25	μV/K
Temperature coefficient of I_{10} $R_{G} = 50 \Omega$	α ιιο		0.3	1.5		1.5	nA/K
Noise voltage (in acc. with DIN 45405; referred to input; $Rs = 2.5 \text{ k}\Omega$)	Vn		3				μV
Output saturation voltage $I_{\Omega} = 10 \text{ mA}$	VQ sat			1			V
Slew rate for non-inverting operation	SR		0.5				V/µs
Slew rate for inverting operation	SR		0.5				V/μs

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Characteristics (TAA 2762)

 $Vs = \pm 2V, RL = 2k\Omega$

Parameter	Symbol	Limit Values T _A = 25 °C			Limit T _A = to 1	Unit	
		min.	typ.	max.	min.	max.	
Input offset voltage, $R_{\rm G} = 50 \Omega$	Vio	- 4		4	- 6	6	mV
Input offset current Input current	110 11	- 70	0.2	70 0.5	- 200	200 0.8	nA μA
Open-loop voltage gain; $f=100$ Hz	Gvo	80			75		dB

Characteristics (TAA 2765)

 $Vs = \pm 5V$ to $\pm 15V$; $R_{\perp} = 2k\Omega$, unless otherwise specified

Parameter	Symbol	Limit Values T _A = 25 °C			Limit Values $T_A = -25$ to 85 °C		Unit
		min.	typ.	max.	min.	max.	1
Open-loop supply current consumption, total	Is		0.5	1.5		1.5	mA
Input offset voltage, $R_{\rm G} = 50 \Omega$	Vio	- 5.5		5.5	- 7	7	mV
Input offset current Input current		- 200	± 80 0.5	200 0.8	- 300	300 1.0	nA μA
Control range $V_{s} = \pm 15 V$ $R_{L} = 620 \Omega$, $V_{s} = \pm 15 V$	Vapp Vapp	14.9 14.9		- 14 - 12.5	14.8 14.8	- 14 - 12	V V
Input impedance, $f = 1 \text{kHz}$	Zı		200				kΩ
Open-loop voltage gain f = 100 Hz $R \perp = 10 \Omega, f = 100$ Hz	G vo G vo	80	85 90		80		dB dB
Output reverse current	IQR			10		20	μA
Common-mode input voltage range	Vic	– Vs +2		Vs – 2	- Vs+3	Vs - 3	V
Common-mode rejection	<i>k</i> cmr	75	83		75		dB
Supply voltage rejection, $Gv = 100$	<i>k</i> svr		25	100		100	μV/V

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Characteristics (TAA 2765) (cont'd)

 $V_{\rm S} = \pm 5 \,\mathrm{V}$ to $\pm 15 \,\mathrm{V}$; $R_{\rm L} = 2 \,\mathrm{k}\Omega$, unless otherwise specified

Parameter	Symbol	Limit Values T _A = 25 °C			Limit Values $T_A = -25$ to 85 °C		Unit
		min.	typ.	max.	min.	max.	
Temperature coefficient of V_{10} $R_{\rm G} = 50 \Omega$			1	15		25	μV/K
Temperature coefficient of $I_{\rm IO}$ $R_{\rm G} = 50 \Omega$	α ιιο		0.3			1.5	nA/K
Noise voltage (in acc. with DIN 45405, referred to input $R_s = 2.5 \text{ k}\Omega$)	Vn		3				μV
Output saturation voltage / a = 10 mA	V Q sat			1			V
Slew rate for non-inverting operation	SR		0.5				V/µs
Slew rate for inverting operation	SR		0.5				V/µs

Characteristics (TAA 2765)

 $V_{\rm S} = \pm 2 \, {\sf V}, R_{\rm L} = 2 \, {\sf k} \Omega$

Parameter	Symbol	Limit Values T _A = 25 °C			Limit T _A = to 8	Unit	
		min.	typ.	max.	min.	max.	
Input offset voltage, $R_G = 50 \Omega$	Vio	- 6		6	- 7.5	7.5	mV
Input offset current Input current	Iю I	- 150	0.2	150 0.6	- 200	200 0.8	nA μA
Open-loop voltage gain; f=100 Hz	G vo	75			75		dB

Note : For typical performance curves, please refer to the data sheets of TAA 765 and TAA 762.